NSN 5961-01-222-8263

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View Online at https://aerobasegroup.com/nsn/5961-01-222-8263
nclosure Material:
Metal
Overall Length:
1.525 inches
Mounting Facility Quantity:
1
nternal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Го-63
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.675 inches
Thread Size:
0.312 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
275.0 collector to emitter reverse voltage and 200.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static,
collector open
Current Rating Per Characteristic:
50.00 amperes source cutoff current
Power Rating Per Characteristic:
280.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
120.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Jnf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0